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ne<mark>x</mark>peria

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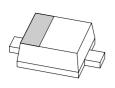
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Kind regards,

Team Nexperia



20 V, 1 A very low V_F MEGA Schottky barrier rectifier in
SOD323F packageRev. 03 — 15 January 2010Product date

Product data sheet

Product profile 1.

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD323F (SC-90) very small and flat lead Surface Mounted Device (SMD) plastic package.

1.2 Features

- Forward current: ≤ 1 A
- Reverse voltage: ≤ 20 V
- Very low forward voltage
- Very small and flat lead SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Inverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current	$T_{sp} \leq 55 \ ^{\circ}C$	-	-	1	А
V _R	reverse voltage		-	-	20	V
V _F	forward voltage	I _F = 1000 mA	[1] -	480	550	mV

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.



20 V, 1 A very low V_F MEGA Schottky barrier rectifier

2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Symbol
1	cathode	[1]	
2	anode		1 🕂 2
			sym001

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. O	r dering	information		
Type number		Package		
		Name	Description	Version
PMEG2010A	ΞJ	SC-90	plastic surface mounted package; 2 leads	SOD323F

4. Marking

Table 4. Mar	king codes	
Type number		Marking code
PMEG2010AEJ	l	EM

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _R	reverse voltage		-	20	V
l _F	forward current	$T_{sp} \le 55 \ ^{\circ}C$	-	1	А
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms}; \delta \le 0.25$	-	5.5	А
I _{FSM}	non-repetitive peak forward current	square wave; t _p = 8 ms	-	10	A
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	<u>[1]</u> -	360	mW
			[2] _	830	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

20 V, 1 A very low V_F MEGA Schottky barrier rectifier

6. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	<u>[1][2]</u>	-	-	350	K/W
	junction to ambient		<u>[1][3]</u>	-	-	150	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		<u>[4]</u>	-	-	55	K/W

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and I_{F(AV)} rating are available on request.

- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [4] Solder point of cathode tab.

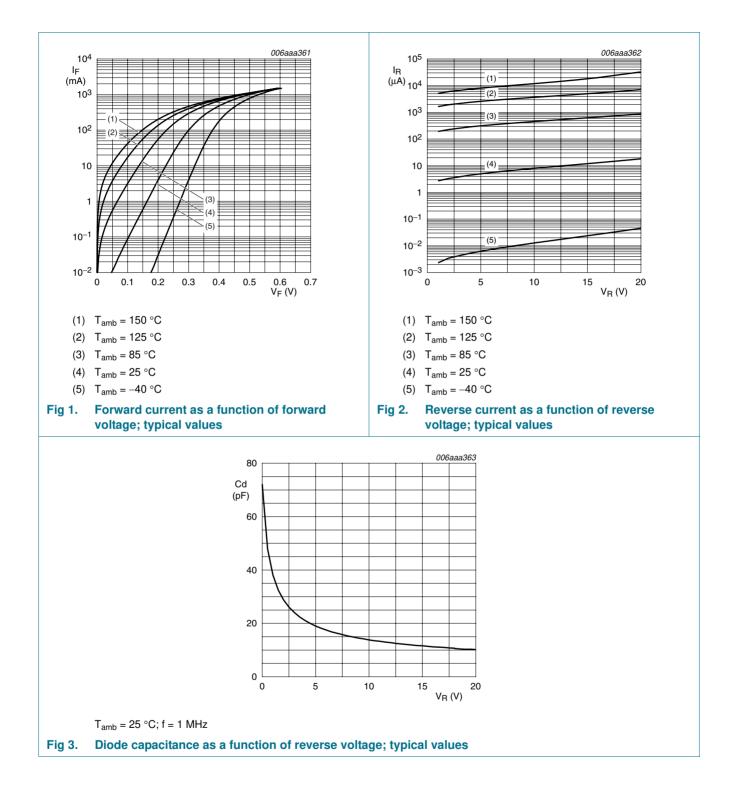
7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

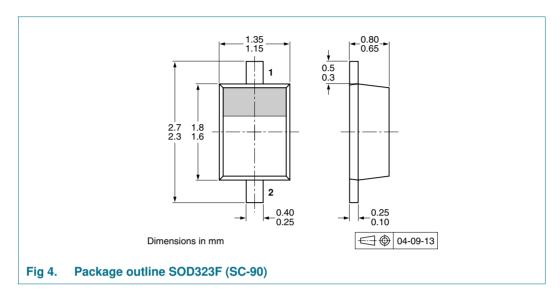
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage		[1]			
	$I_F = 10 \text{ mA}$	-	240	270	mV	
	I _F = 100 mA	-	300	350	mV	
	I _F = 500 mA	-	400	460	mV	
	I _F = 1000 mA	-	480	550	mV	
I _R reverse current	V _R = 5 V	-	5	10	μA	
		V _R = 8 V	-	7	20	μA
		V _R = 10 V	-	8	30	μA
	V _R = 15 V	-	10	50	μA	
		V _R = 20 V	-	15	70	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz	-	40	50	pF

20 V, 1 A very low V_F MEGA Schottky barrier rectifier



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8. Package outline



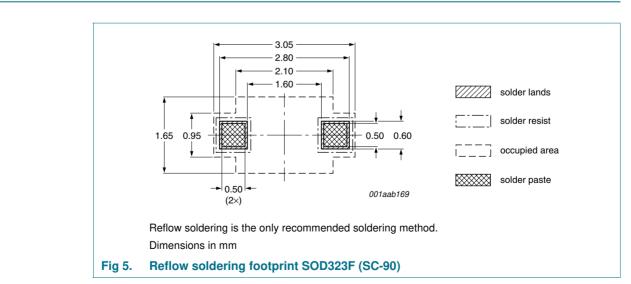
9. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing	quantity
			3000	10000
PMEG2010AEJ	SOD323F	4 mm pitch, 8 mm tape and reel	-115	-135

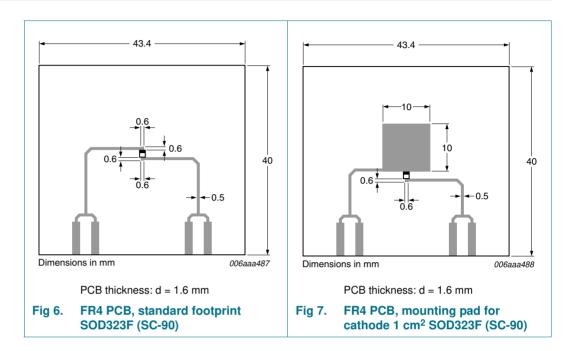
[1] For further information and the availability of packing methods, see Section 14.



10. Soldering

20 V, 1 A very low V_F MEGA Schottky barrier rectifier

11. Mounting



20 V, 1 A very low V_F MEGA Schottky barrier rectifier

12. Revision history

Table 9. Revision his	story			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG2010AEJ_3	20100115	Product data sheet	-	PMEG2010AEJ_2
Modifications:		eet was changed to reflect w legal definitions and disc		
PMEG2010AEJ_2	20051014	Product data sheet	-	PMEG2010AEJ_1
PMEG2010AEJ_1	20050302	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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